

Spectral hole-burning glasses

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288	<p>Spectral hole burning in sol-gel-derived Eu³⁺-doped Al₂O₃-B₂O₃-SiO₂ glass H. You, T. Hayakawa, and M. Nogami Adv. Mater. Res. 11-12, 201~204 (2006).</p>
274	<p>Persistent spectral hole burning of Eu³⁺ ions in TiO₂-SiO₂ glass prepared by sol-gel method H. You and M. Nogami J. Alloy and Compounds, 408/412, 796~99 (2006).</p>
273	<p>Influences of Al³⁺ and Eu³⁺ concentration on PSHB properties of melt-quenched Al₂O₃-SiO₂ glasses Gil Jae Park, T. Hayakawa and M. Nogami J. Alloy and Compounds, 408/412, 721~23 (2006).</p>
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